

PHILIPS INTERNATIONAL

56E D

7110826 0041250 7T7 PHIN

ULTRA FAST-RECOVERY RECTIFIER DIODES

T-03-17

Glass-passivated, high-efficiency epitaxial rectifier diodes in DO-4 metal envelopes, featuring low forward voltage drop, ultra fast reverse recovery times, very low stored charge and soft-recovery characteristic. They are intended for use in switched-mode power supplies and high-frequency circuits in general, where both low conduction losses and low switching losses are essential. The series consists of normal polarity (cathode to stud) types.

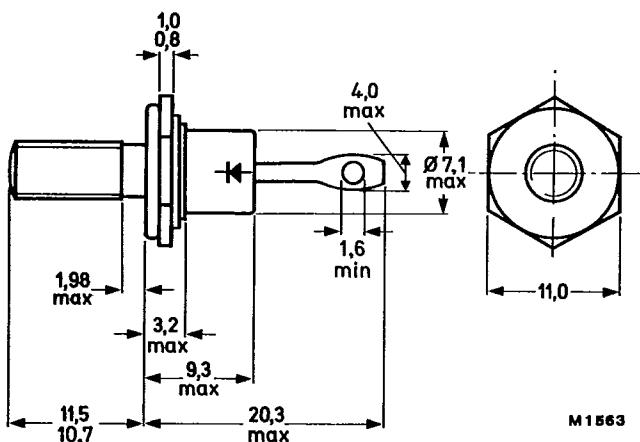
QUICK REFERENCE DATA

	BYR30-500	600	700	
Repetitive peak reverse voltage	V _{RRM}	max. 500	600	700 V
Average forward current	I _{F(AV)}	max.	14	A
Forward voltage	V _F	<	1.5	V
Reverse recovery time	t _{rr}	<	100	ns

MECHANICAL DATA

Dimensions in mm

Fig.1 DO-4; with metric M5 stud ($\phi 5$ mm); e.g. BYR30-600,
with 10-32 UNF stud ($\phi 4.83$ mm) e.g. BYR30-600U.



Net mass: 6 g

Supplied with device: 1 nut, 1 lock washer

Diameter of clearance hole: max. 5.2 mm

Torque on nut: min. 0.9 Nm (9 kg cm)
max. 1.7 Nm (17 kg cm)

Accessories supplied on request:

56295a (mica washer);

Nut dimensions across the flats:

56295b (PTFE ring);

M5: 8.0 mm; 10-32 UNF: 9.5 mm

56295c (insulating bush).

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RATINGS

Limiting values in accordance with the Absolute Maximum System (IEC 134).

Voltages

		BYR30-500	600	700	
Repetitive peak reverse voltage	V_{RRM}	max.	500	600	700
Crest working reverse voltage	V_{RWM}	max.	400	500	500
Continuous reverse voltage*	V_R	max.	400	500	500

Currents

Average forward current; switching

losses negligible up to 100 kHz;

→ square wave; $\delta = 0.5$; up to $T_{mb} = 98^\circ\text{C}$	$I_{F(AV)}$	max.	14	A
→ sinusoidal; up to $T_{mb} = 106^\circ\text{C}$	$I_{F(AV)}$	max.	12.5	A

R.M.S. forward current

R.M.S. forward current	$I_{F(RMS)}$	max.	20	A
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Repetitive peak forward current

 $t_p = 20 \mu\text{s}, \delta = 0.02$

Repetitive peak forward current	I_{FRM}	max.	360	A
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Non-repetitive peak forward current
half sinewave; $T_j = 150^\circ\text{C}$ prior to
surge; with reapplied V_{RWM} max $t = 10 \text{ ms}$

Non-repetitive peak forward current	I_{FSM}	max.	150	A
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 $t = 8.3 \text{ ms}$

Non-repetitive peak forward current	I_{FSM}	max.	180	A
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 $I^2 t$ for fusing ($t = 10 \text{ ms}$)

$I^2 t$ for fusing ($t = 10 \text{ ms}$)	$I^2 t$	max.	112	A^2s
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Temperatures

Storage temperature

Storage temperature	T_{stg}		-55 to +150	$^\circ\text{C}$
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Junction temperature

Junction temperature	T_j	max.	150	$^\circ\text{C}$
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THERMAL RESISTANCE

From junction to mounting base

From junction to mounting base	$R_{th j\text{-}mb}$	=	2.0	K/W
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From mounting base to heatsink:

a. with heatsink compound

a. with heatsink compound	$R_{th mb\text{-}h}$	=	0.3	K/W
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b. without heatsink compound

b. without heatsink compound	$R_{th mb\text{-}h}$	=	0.6	K/W
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Transient thermal impedance; $t = 1 \text{ ms}$

Transient thermal impedance; $t = 1 \text{ ms}$	$Z_{th j\text{-}mb}$	=	0.3	K/W
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MOUNTING INSTRUCTIONS

The top connector should be neither bent nor twisted; it should be soldered into the circuit so that there is no strain on it.

During soldering the heat conduction to the junction should be kept to a minimum.

*To ensure thermal stability: $R_{th j\text{-}a} \leq 5.6 \text{ K/W}$.

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CHARACTERISTICS

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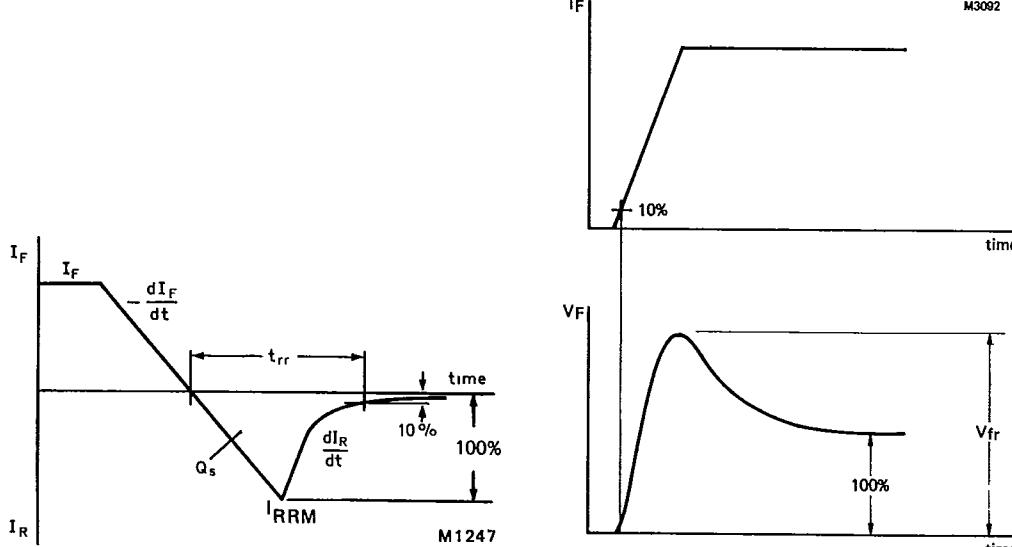
Forward voltage

 $I_F = 15 \text{ A}; T_j = 150^\circ\text{C}$ $V_F < 1.5 \text{ V}^*$ $I_F = 50 \text{ A}; T_j = 25^\circ\text{C}$ $V_F < 2.0 \text{ V}^*$

Reverse current

 $V_R = V_{RWM} \text{ max}; T_j = 100^\circ\text{C}$ $I_R < 0.4 \text{ mA}$ $V_R = V_{RWM} \text{ max}; T_j = 25^\circ\text{C}$ $I_R < 25 \mu\text{A}$

Reverse recovery when switched from

 $I_F = 1 \text{ A} \text{ to } V_R \geq 30 \text{ V} \text{ with } -dI_F/dt = 100 \text{ A}/\mu\text{s};$
 $T_j = 25^\circ\text{C}; \text{recovery time}$ $t_{rr} < 100 \text{ ns}$ $I_F = 2 \text{ A} \text{ to } V_R \geq 30 \text{ V} \text{ with } -dI_F/dt = 20 \text{ A}/\mu\text{s};$
 $T_j = 25^\circ\text{C}; \text{recovered charge}$ $Q_s < 220 \text{ nC}$ $I_F = 10 \text{ A} \text{ to } V_R \geq 30 \text{ V} \text{ with } -dI_F/dt = 50 \text{ A}/\mu\text{s};$
 $T_j = 100^\circ\text{C}; \text{peak recovery current}$ $I_{RRM} < 8 \text{ A}$ Forward recovery when switched to $I_F = 10 \text{ A}$
with $dI_F/dt = 10 \text{ A}/\mu\text{s}; T_j = 25^\circ\text{C}$ $V_{fr} \text{ typ. } 5.1 \text{ V}$ Fig.2 Definition of t_{rr} , Q_s and I_{RRM} .Fig.3 Definition of V_{fr} .

*Measured under pulse conditions to avoid excessive dissipation.

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SQUARE-WAVE OPERATION

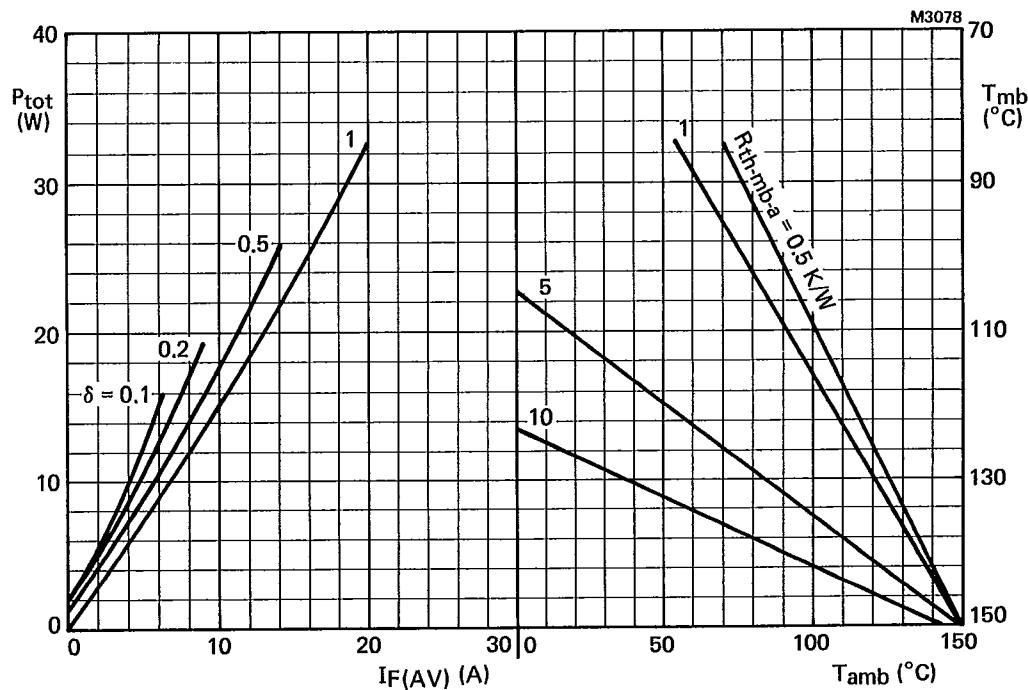
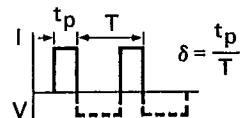


Fig.4 The right-hand part shows the relationship between the power (derived from the left-hand part) and the maximum permissible temperatures. Power includes reverse current losses and switching losses up to $f = 100$ kHz.



$$I_F(AV) = I_F(RMS) \times \sqrt{\delta}$$

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SINUSOIDAL OPERATION

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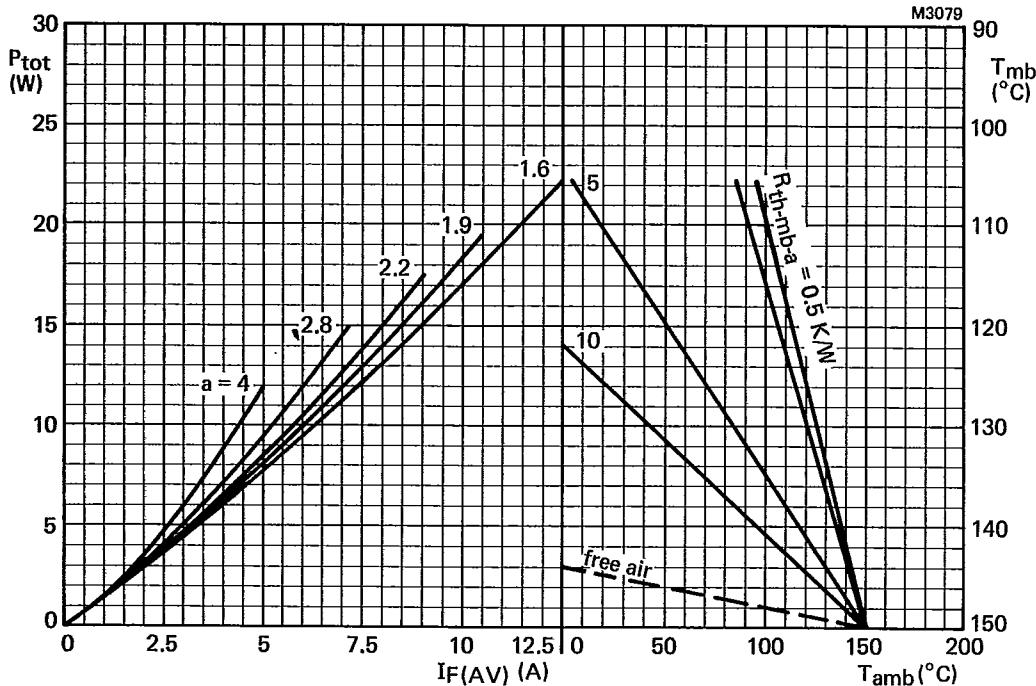


Fig.5 The right-hand part shows the interrelationship between the power (derived from the left-hand part) and the maximum permissible temperatures.

$$a = \text{form factor} = I_F(\text{RMS})/I_F(\text{AV}).$$

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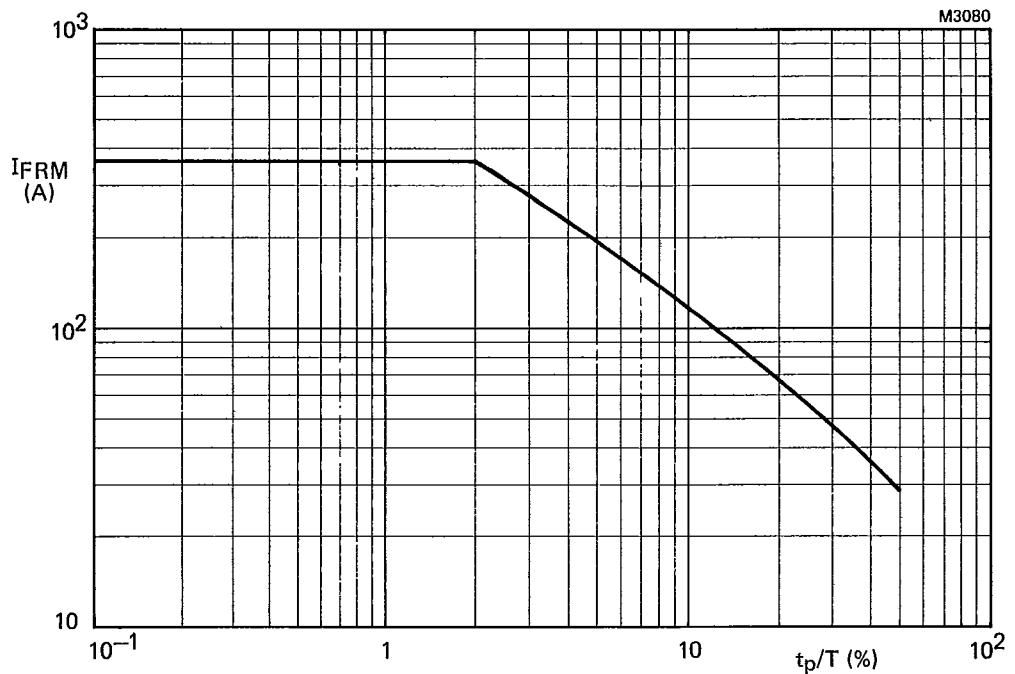
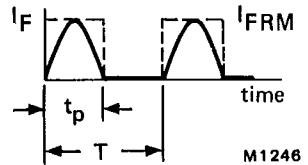
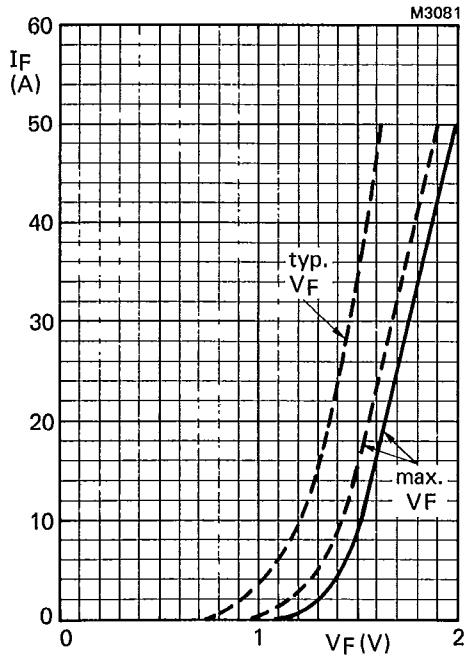


Fig.6 Maximum permissible repetitive peak forward current for square or sinusoidal currents;
 $1 \mu\text{s} < t_p < 1 \text{ ms}$.

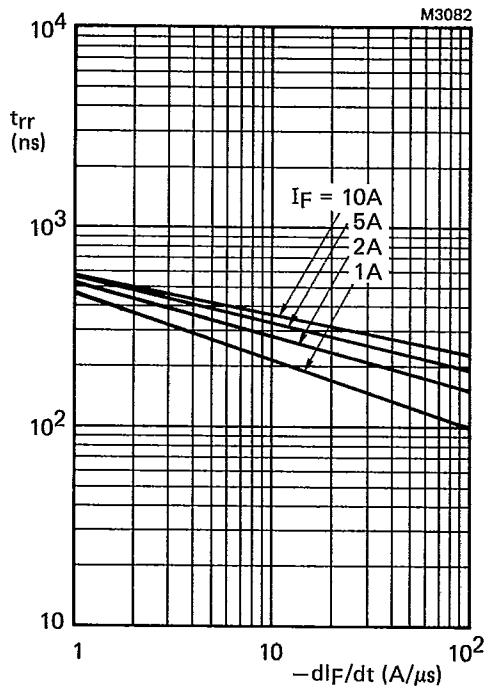
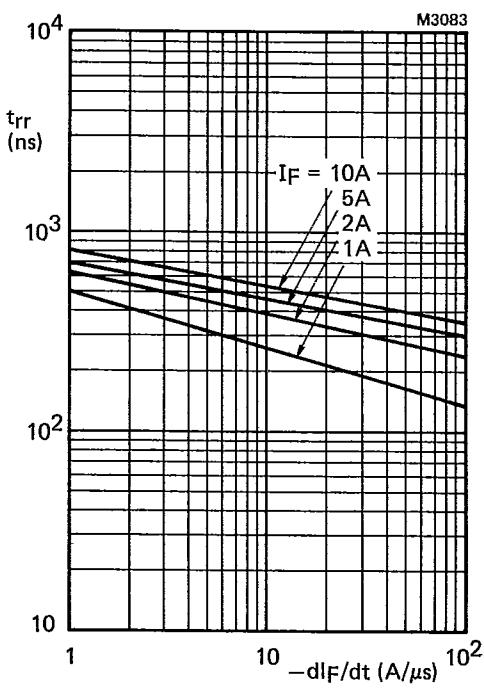
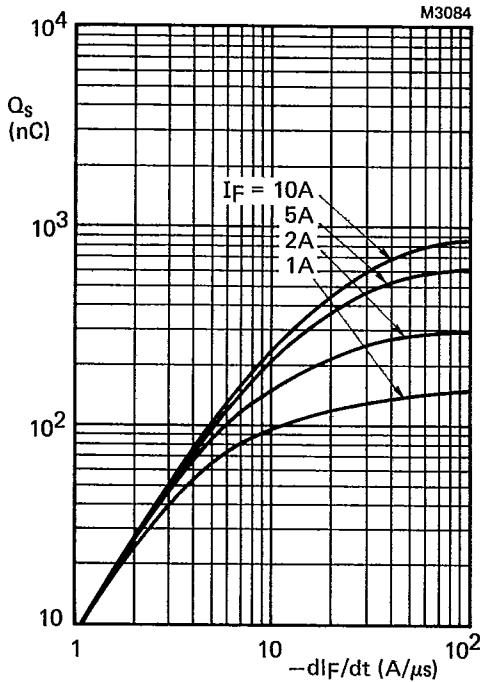


Definition of I_{FRM}
and t_p/T .

Fig.7 — $T_j = 25^\circ\text{C}$ — $T_j = 150^\circ\text{C}$.

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Fig.8 Maximum t_{rr} at $T_j = 25^\circ C$.Fig.9 Maximum t_{rr} at $T_j = 100^\circ C$.Fig.10 Maximum Q_s at $T_j = 25^\circ C$.

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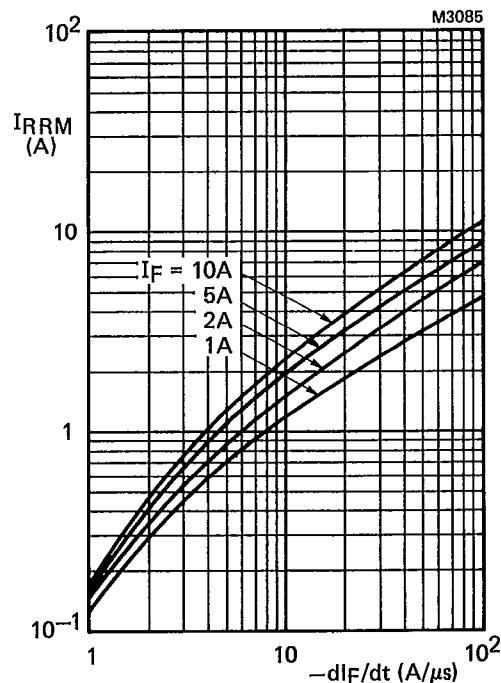
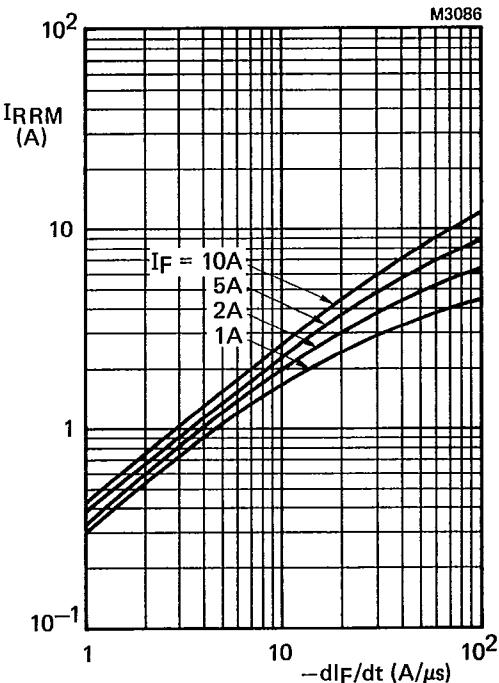
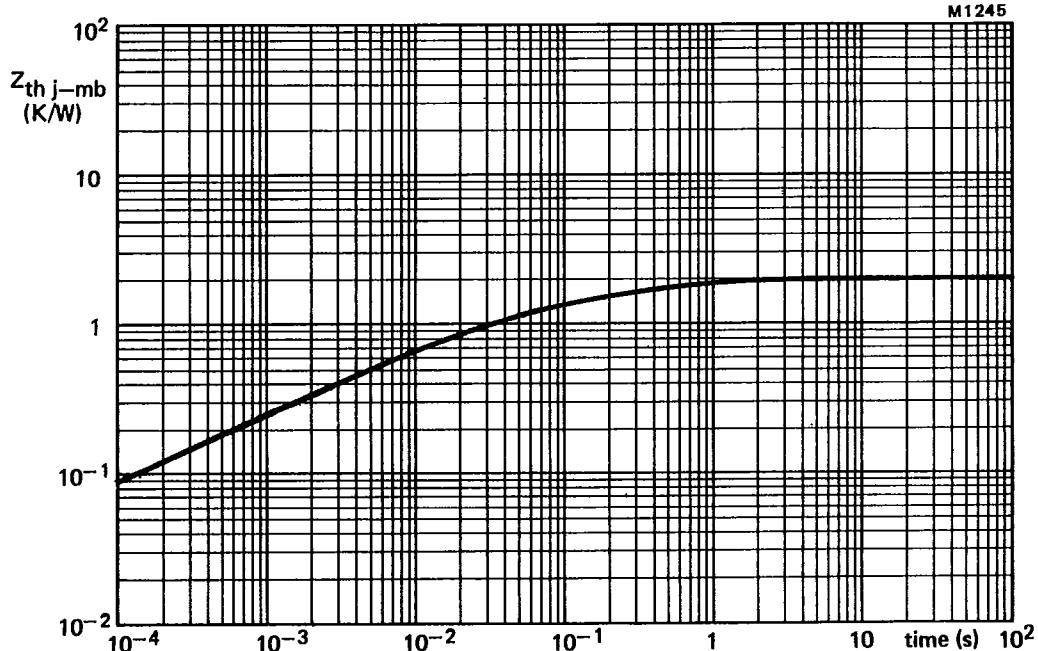
Fig.11 Maximum I_{RRM} at $T_j = 25^\circ C$.Fig.12 Maximum I_{RRM} at $T_j = 100^\circ C$.

Fig.13 Transient thermal impedance.